Electronic Circuits

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FET Amplifiers

FETs provide:

- Excellent voltage gain High input impedance Low-power consumption Good frequency range

FET Small-Signal Model

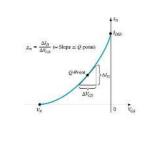
Transconductance

The relationship of a change in ${\rm I}_{\rm D}$ to the corresponding change in ${\rm V}_{\rm GS}$ is called transconductance

Transconductance is denoted g_m and given by:

$$g_m = \frac{\Delta I_D}{\Delta V_{GG}}$$

Graphical Determination of g_m



Mathematical Definitions of g_m

$$\begin{aligned} \mathbf{g}_{m} &= \frac{\Delta I_{D}}{\Delta V_{GS}} \\ \mathbf{g}_{m} &= \frac{2 I_{DSS}}{|V_{P}|} \left[1 - \frac{V_{GS}}{V_{P}} \right] \end{aligned}$$

Where
$$V_{GS}$$
 =0V g_{m0} = $\frac{2I_{DSS}}{|V_P|}$ g_m = $g_{m0} \int_{-\infty}^{\infty} 1 - \frac{V_{GS}}{N}$

$$V_P$$
 $\sqrt{I_{DSS}}$
$$g_m = g_{m0} \left(1 - \frac{V_{GS}}{V_P} \right) = g_{m0} \sqrt{\frac{I_D}{I_{DSS}}}$$

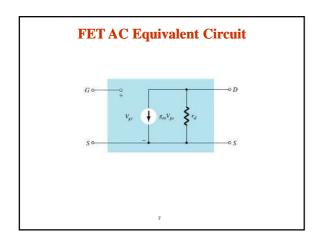
FET Impedance

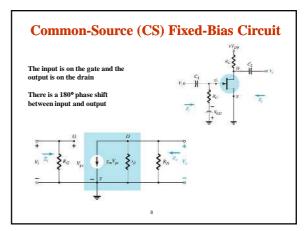
$$Z_i = \infty \Omega$$

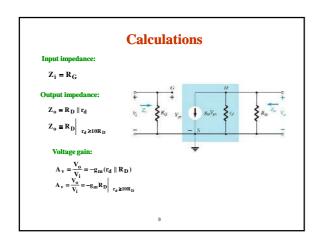
$$Z_o = r_d = \frac{1}{y_{os}}$$

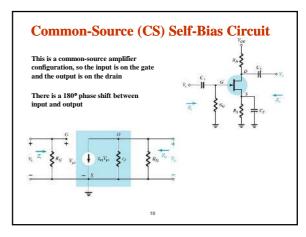
$$r_d = \frac{\Delta v_{DS}}{\Delta I_D} |_{V_{GS} = constant}$$

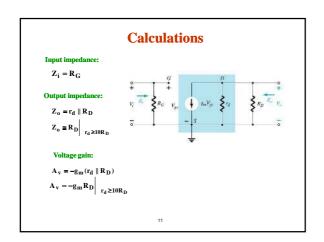
 $y_{os} = admittance parameter listed on FET specification sheets.$

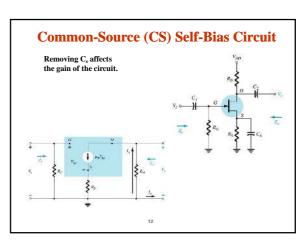


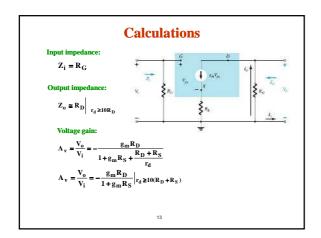


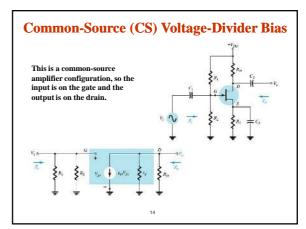


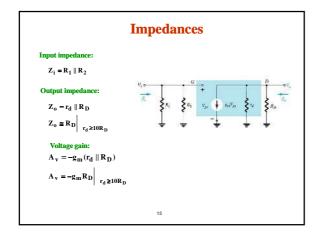


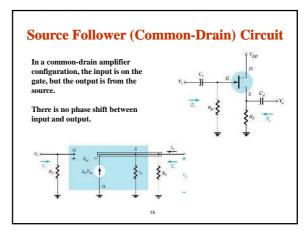


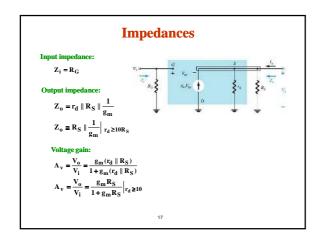


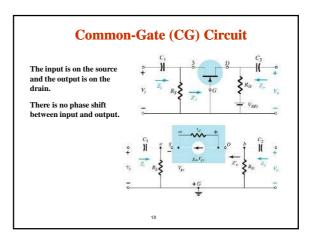


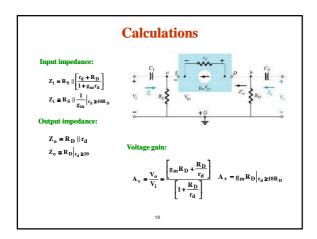


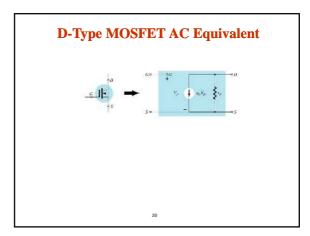


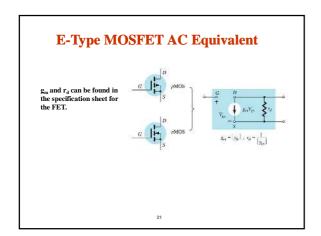


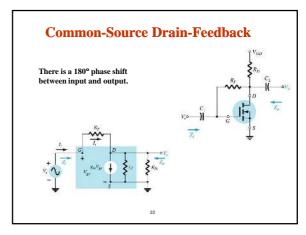


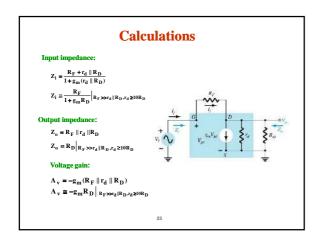


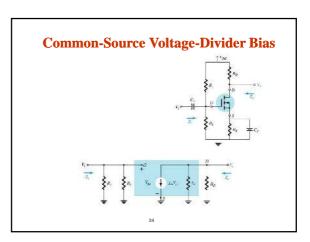


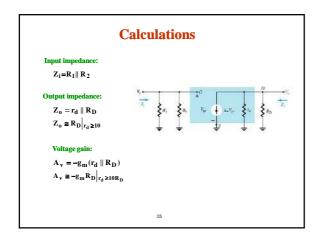


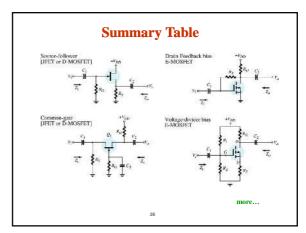


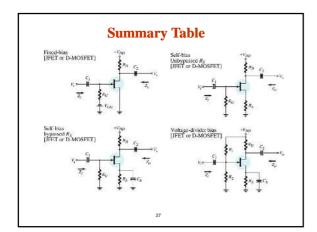


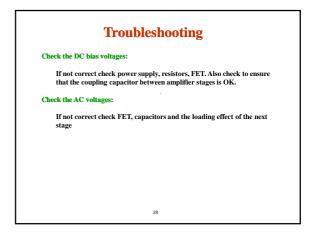












Practical Applications Three-Channel Audio Mixer Silent Switching Phase Shift Networks Motion Detection System